SWITCHMODE™ Power Rectifier

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- Pb-Free Package is Available*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

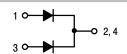
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B Machine Model C

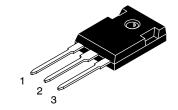


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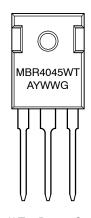
SCHOTTKY BARRIER RECTIFIER 40 AMPERES, 45 VOLTS





TO-247AC CASE 340L STYLE 2

MARKING DIAGRAM



MBR4045WT = Device Code A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MBR4045WT	TO-247	30 Units/Rail
MBR4045WTG	TO-247 (Pb-Free)	30 Units/Rail

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Max 45	Unit V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R		
Average Rectified Forward Current (Rated V _R , T _C = 125°C) Per Diode Per Device	l _{F(AV)}	20 40	А
Peak Repetitive Forward Current, (Rated V_R , Square Wave, 20 kHz, T_C = 90°C) Per Diode	I _{FRM}	40	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	400	А
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	I _{RRM}	2.0	Α
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	175	°C
Voltage Rate of Change	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Max	Unit
Maximum Thermal Resistance, Junction-to-Case	Min. Pad	$R_{ heta JC}$	1.4	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	Min. Pad	$R_{\theta JA}$	50.1	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typical	Max	Unit
Instantaneous Forward Voltage (Note 2)	V _F				V
@ I _F = 20 Amps, T _J = 25°C		-	0.52	0.70	
@ I _F = 20 Amps, T _J = 125°C		-	0.47	0.60	
@ I _F = 40 Amps, T _J = 25°C		_	0.65	0.80	
@ I _F = 40 Amps, T _J = 125°C		-	0.63	0.75	
Instantaneous Reverse Current (Note 2)	I _R				mA
@ Rated DC Voltage, T _J = 25°C		_	0.09	1.0	
@ Rated DC Voltage, T _J = 100°C		-	7.5	50	

^{2.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle < 2.0%

^{1.} The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

TYPICAL ELECTRICAL CHARACTERISTICS

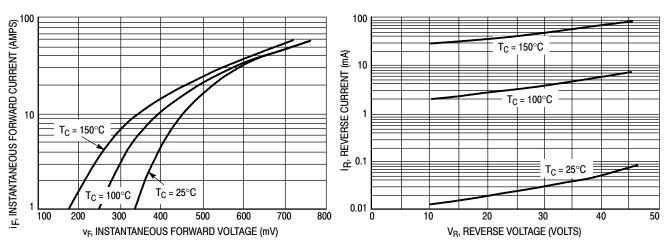


Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current

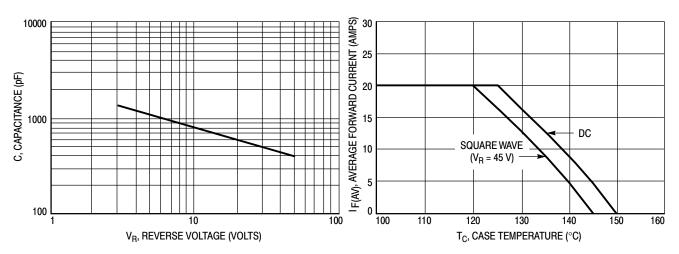
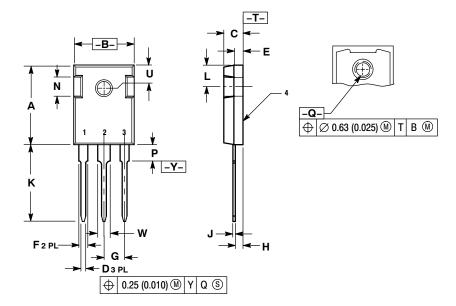


Figure 3. Typical Capacitance Per Leg

Figure 4. Current Derating Per Leg

PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE E



- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	20.32	21.08	0.800	8.30	
В	15.75	16.26	0.620	0.640	
С	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
Е	1.90	2.60	0.075	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45 BSC		0.215 BSC		
Н	1.50	2.49	0.059	0.098	
J	0.40	0.80	0.016	0.031	
K	19.81	20.83	0.780	0.820	
L	5.40	6.20	0.212	0.244	
N	4.32	5.49	0.170	0.216	
P		4.50		0.177	
Q	3.55	3.65	0.140	0.144	
υ	6.15 BSC		0.242 BSC		
W	2.87	3.12	0.113	0.123	

STYLE 2:

- PIN 1. ANODE 2. CATHODE (S)
 - ANODE 2
 - 4. CATHODES (S)

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